Low-power 2-input EXCLUSIVE-OR gate Rev. 3 — 21 July 2021

Product data sheet

1. General description

The 74AUP1G86-Q100 is a single 2-input EXCLUSIVE-OR gate. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A, exceeds 5000 V
 - HBM JESD22-A114F Class 3A, exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

3. Ordering information

Table 1. Ordering information

| Type number | Package | ckage | | | | | | | |
|------------------|-------------------|--------|---|----------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| 74AUP1G86GW-Q100 | -40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm | SOT353-1 | | | | | |

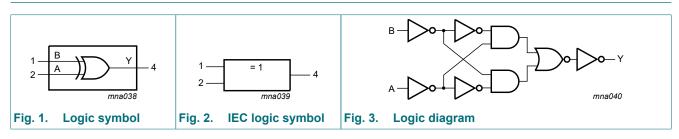
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4. Marking

| Table 2. Marking | | | | |
|------------------|------------------|--|--|--|
| Type number | Marking code [1] | | | |
| 74AUP1G86GW-Q100 | рН | | | |

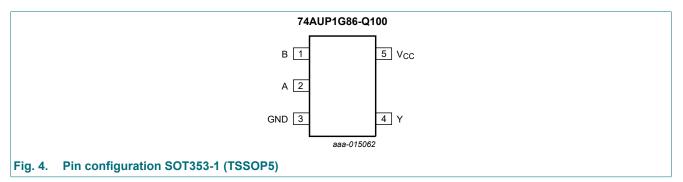
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|----------------|
| В | 1 | data input |
| A | 2 | data input |
| GND | 3 | ground (0 V) |
| Y | 4 | data output |
| V _{CC} | 5 | supply voltage |

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

| Input | | Output |
|-------|---|--------|
| Α | В | Y |
| L | L | L |
| L | Н | Н |
| н | L | Н |
| Н | Н | L |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--|------|------|------|
| V _{CC} | supply voltage | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V _I < 0 V | -50 | - | mA |
| VI | input voltage | [1] | -0.5 | +4.6 | V |
| I _{OK} | output clamping current | V _O < 0 V | -50 | - | mA |
| Vo | output voltage | Active mode and Power-down mode [1] | -0.5 | +4.6 | V |
| I _O | output current | $V_{O} = 0 V \text{ to } V_{CC}$ | - | ±20 | mA |
| I _{CC} | supply current | | - | +50 | mA |
| I _{GND} | ground current | | -50 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2] | - | 250 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|----------------------------------|-----|-----------------|------|
| V _{CC} | supply voltage | | 0.8 | 3.6 | V |
| VI | input voltage | | 0 | 3.6 | V |
| Vo | output voltage | Active mode | 0 | V _{CC} | V |
| | | Power-down mode; V_{CC} = 0 V | 0 | 3.6 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 0.8 V to 3.6 V | 0 | 200 | ns/V |

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|----------------------|---|--|------------------------|-----|------------------------|------|
| T _{amb} = 2 | 25 °C | | | | 1 | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | $0.65 \times V_{CC}$ | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | 0.35 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |
| V _{OH} | HIGH-level output voltage | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | |
| | | I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.75 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.11 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.32 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 2.05 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.9 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.72 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.6 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | |
| | | I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | $0.3 \times V_{CC}$ | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.31 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.31 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.31 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.44 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.31 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.44 | V |
| lı | input leakage current | V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V | - | - | ±0.1 | μA |
| I _{OFF} | power-off leakage current | $V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$ | - | - | ±0.2 | μA |
| ΔI _{OFF} | additional power-off leakage current | $V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$ | - | | | μA |
| I _{CC} | supply current | $V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | - | - | 0.5 | μA |
| ΔI _{CC} | additional supply current | $V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V} \text{ [1]}$ | - | - | 40 | μA |
| CI | input capacitance | V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC} | - | 0.8 | - | pF |
| Co | output capacitance | $V_{O} = GND; V_{CC} = 0 V$ | - | 1.7 | - | pF |

Low-power 2-input EXCLUSIVE-OR gate

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|----------------------|---|--|------------------------|-----|------------------------|------|
| T _{amb} = - | 40 °C to +85 °C | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | $0.65 \times V_{CC}$ | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | $0.35 \times V_{CC}$ | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |
| V _{ОН} | HIGH-level output voltage | $V_{I} = V_{IH}$ or V_{IL} | | | | |
| | | I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.7 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 1.03 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.30 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.97 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.85 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.67 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.55 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_{I} = V_{IH}$ or V_{IL} | | | | |
| | | I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | $0.3 \times V_{CC}$ | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.37 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.35 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.33 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.45 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.33 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.45 | V |
| l _l | input leakage current | V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V | - | - | ±0.5 | μA |
| I _{OFF} | power-off leakage current | $V_{1} \text{ or } V_{0} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$ | - | - | ±0.5 | μA |
| ∆I _{OFF} | additional power-off leakage current | $V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$ | - | - | ±0.6 | μA |
| I _{CC} | supply current | $V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | - | - | 0.9 | μA |
| Δl _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V [1] | - | - | 50 | μA |
| T _{amb} = - | 40 °C to +125 °C | | I | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | 0.75 × V _{CC} | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | 0.70 × V _{CC} | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | 0.25 × V _{CC} | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | 0.30 × V _{CC} | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | _ | _ | 0.9 | V |

Low-power 2-input EXCLUSIVE-OR gate

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|-------------------|---|--|------------------------|-----|------------------------|------|
| V _{OH} | HIGH-level output voltage | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | |
| | | I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V | V _{CC} - 0.11 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | $0.6 \times V_{CC}$ | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 0.93 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.17 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.77 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.67 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.40 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 3.0 V | 2.30 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | |
| | | I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V | - | - | 0.11 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.33 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.41 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.39 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.36 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.50 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.36 | V |
| | | I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.50 | V |
| I | input leakage current | V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V | - | - | ±0.75 | μA |
| I _{OFF} | power-off leakage current | $V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$ | - | - | ±0.75 | μA |
| ΔI _{OFF} | additional power-off leakage current | $V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$ | - | - | ±0.75 | μA |
| I _{CC} | supply current | $V_1 = GND \text{ or } V_{CC}; I_0 = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | - | - | 1.4 | μA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V [1] | - | - | 75 | μA |

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6

| Symbol | Parameter | Conditions | Min | Тур [1] | Max | Unit |
|----------------------|-----------------------------|------------------------------------|-----|---------|------|------|
| T _{amb} = 2 | 5 °C; C _L = 5 pF | | | | | _ |
| t _{pd} | propagation delay | A or B to Y; see <u>Fig. 5</u> [2] | | | | |
| | | V _{CC} = 0.8 V | - | 21.2 | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 2.3 | 5.9 | 13.1 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 1.8 | 4.1 | 7.7 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 1.5 | 3.3 | 5.9 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 1.2 | 2.6 | 4.4 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 1.0 | 2.3 | 4.0 | ns |

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| Symbol | Parameter | Conditions | | Min | Тур [1] | Max | Unit |
|----------------------|-------------------------------|------------------------------------|-----|-----|-----------|------|------|
| T _{amb} = 2 | 25 °C; C _L = 10 pF | | I | | | | |
| t _{pd} | propagation delay | A or B to Y; see <u>Fig. 5</u> | [2] | | | | |
| | | V _{CC} = 0.8 V | | - | 24.7 | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | | 2.6 | 6.8 | 14.8 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 2.2 | 4.8 | 8.7 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 1.8 | 3.9 | 6.7 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | | 1.5 | 3.1 | 5.2 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | | 1.3 | 2.9 | 4.8 | ns |
| T _{amb} = 2 | 25 °C; C _L = 15 pF | | I | | · · · · · | | _ |
| t _{pd} | propagation delay | A or B to Y; see Fig. 5 | [2] | | | | |
| | | V _{CC} = 0.8 V | | - | 28.2 | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | | 3.0 | 7.6 | 16.5 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 2.4 | 5.3 | 9.6 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 2.1 | 4.4 | 7.5 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | 1.8 | 3.6 | 5.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | | 1.6 | 3.3 | 5.4 | ns |
| T _{amb} = 2 | 25 °C; C _L = 30 pF | | I | | 1 1 | | |
| t _{pd} | propagation delay | A or B to Y; see Fig. 5 | [2] | | | | |
| | | V _{CC} = 0.8 V | | - | 38.5 | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | | 3.9 | 9.9 | 21.5 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 3.2 | 6.9 | 12.5 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 2.8 | 5.7 | 9.8 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | | 2.4 | 4.7 | 7.6 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | | 2.2 | 4.4 | 7.1 | ns |
| T _{amb} = 2 | 5 °C | | I | | | | |
| C _{PD} | power dissipation | $f = 1 MHz; V_I = GND to V_{CC}$ | [3] | | | | |
| | capacitance | V _{CC} = 0.8 V | | - | 2.7 | - | pF |
| | | V _{CC} = 1.1 V to 1.3 V | | - | 2.9 | - | pF |
| | | V _{CC} = 1.4 V to 1.6 V | | - | 3.0 | - | pF |
| | | V _{CC} = 1.65 V to 1.95 V | | - | 3.1 | - | pF |
| | | V_{CC} = 2.3 V to 2.7 V | | - | 3.6 | - | pF |
| | | V _{CC} = 3.0 V to 3.6 V | | - | 4.2 | - | pF |

[1] All typical values are measured at nominal V_{CC}.

[2] t_{pd} is the same as t_{PHL} and t_{PLH} . [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Low-power 2-input EXCLUSIVE-OR gate

Table 9. Dynamic characteristics

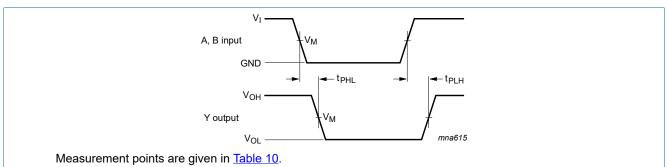
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6

| Symbol | Parameter | Conditions | | -40 °C t | o +85 °C | -40 °C to +125 °C | | Unit |
|----------------------|-------------------|------------------------------------|-----|----------|----------|-------------------|------|------|
| | | | - | Min | Max | Min | Max | |
| C _L = 5 p | F | 1 | | | | 1 | | |
| t _{pd} | propagation delay | A or B to Y; see Fig. 5 | [1] | | | | | |
| | | V _{CC} = 1.1 V to 1.3 V | | 2.1 | 14.3 | 2.1 | 15.8 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 1.6 | 8.8 | 1.6 | 9.7 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 1.4 | 6.9 | 1.4 | 7.6 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | | 1.1 | 5.3 | 1.1 | 5.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | | 0.9 | 4.7 | 0.9 | 5.2 | ns |
| C _L = 10 | pF | 1 | | | | 1 | | 1 |
| t _{pd} | propagation delay | A or B to Y; see <u>Fig. 5</u> | [1] | | | | | |
| | | V _{CC} = 1.1 V to 1.3 V | | 2.4 | 16.2 | 2.4 | 17.9 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 1.9 | 10.0 | 1.9 | 11.0 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 1.7 | 8.0 | 1.7 | 8.8 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | | 1.4 | 6.2 | 1.4 | 6.9 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | | 1.3 | 5.6 | 1.3 | 6.2 | ns |
| C _L = 15 | pF | 1 | | | | 1 | | 1 |
| t _{pd} | propagation delay | A or B to Y; see <u>Fig. 5</u> | [1] | | | | | |
| | | V _{CC} = 1.1 V to 1.3 V | | 2.7 | 18.1 | 2.7 | 20.0 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 2.2 | 11.3 | 2.2 | 12.5 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 1.9 | 9.0 | 1.9 | 9.9 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | | 1.6 | 7.0 | 1.6 | 7.7 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | | 1.5 | 6.4 | 1.5 | 7.1 | ns |
| C _L = 30 | pF | 1 | | | | 1 | | 1 |
| t _{pd} | propagation delay | A or B to Y; see <u>Fig. 5</u> | [1] | | | | | |
| | | V _{CC} = 1.1 V to 1.3 V | | 3.5 | 24.1 | 3.5 | 26.6 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | | 2.8 | 14.8 | 2.8 | 16.3 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 2.5 | 11.7 | 2.5 | 12.9 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | | 2.2 | 9.1 | 2.2 | 10.1 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | | 2.1 | 8.3 | 2.1 | 9.2 | ns |

 $\label{eq:tpd} [1] \quad t_{pd} \text{ is the same as } t_{PHL} \text{ and } t_{PLH}.$

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11.1. Waveforms and test circuit



Logic levels: V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig. 5. The data input (A or B) to output (Y) propagation delays

Table 10. Measurement points

| Supply voltage | Output | Input | | | |
|-----------------|-----------------------|-----------------------|-----------------|-------------|--|
| V _{cc} | V _M | V _M | VI | $t_r = t_f$ | |
| 0.8 V to 3.6 V | 0.5 × V _{CC} | 0.5 × V _{CC} | V _{CC} | ≤ 3.0 ns | |

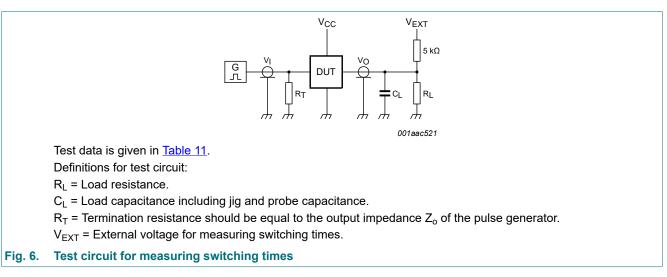


Table 11. Test data

| Supply voltage | Load | | V _{EXT} | | |
|-----------------|------------------------------|--------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| V _{cc} | CL | R _L [1] | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open | GND | 2 × V _{CC} |

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 $M\Omega$

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12. Package outline

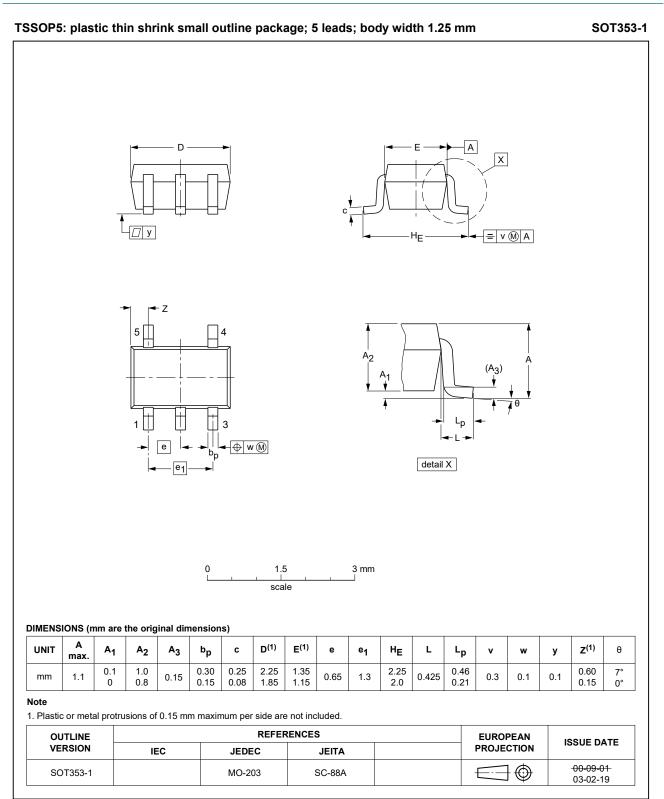


Fig. 7. Package outline SOT353-1 (TSSOP5)

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13. Abbreviations

| Acronym | Description |
|---------|-------------------------|
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MIL | Military |
| MM | Machine Model |

14. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------------|---|--------------------|---------------|--------------------|
| 74AUP1G86_Q100 v.3 | 20210721 | Product data sheet | - | 74AUP1G86_Q100 v.2 |
| Modifications: | <u>Section 1</u> and <u>Section 2</u> updated. <u>Section 8</u>: Derating values for P_{tot} total power dissipation updated. | | | |
| 74AUP1G86_Q100 v.2 | 20180907 | Product data sheet | - | 74AUP1G86_Q100 v.1 |
| Modifications: | The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. | | | |
| 74AUP1G86_Q100 v.1 | 20141020 | Product data sheet | - | - |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|-----------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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